

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	60	@ad<="20030320" and 'trench' with 'split-gate' with 'flash memory'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 09:34
L4	2	("5495441").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/17 09:45
L5	1	"5343063".PN.	USPAT; USOCR	OR	ON	2004/12/17 09:45
L6	1	"5313421".PN.	USPAT; USOCR	OR	ON	2004/12/17 09:45
L7	1	"5291439".PN.	USPAT; USOCR	OR	ON	2004/12/17 09:48
L8	0	@ad<="20030320" and 'flash memory' same 'control gate' with 'cap layer' with 'side wall'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 10:50
L9	2	@ad<="20030320" and 'control gate' with 'cap layer' with 'side wall'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 11:00
L11	61	@ad<="20030320" and 'control gate' with 'spacer' same 'cap'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 11:19
L12	1	"6476440".PN.	USPAT; USOCR	OR	ON	2004/12/17 11:18
L13	1	"6291297".PN.	USPAT; USOCR	OR	ON	2004/12/17 11:18
L14	358	@ad<="20030320" and 'control gate' same 'flash memory' same 'select' with 'gate'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 11:20
L15	190	@ad<="20030320" and 'control gate' same 'flash memory' with 'select' with 'gate'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 11:20
S1	2	"20040183124"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:04

S2	38	Hsu.in. and 'Powerchip Semiconductor'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:18
S3	392	@ad<="20030320" and 'Flash memory' with 'gate' with 'trench'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 09:23
S4	21	@ad<="20030320" and 'Flash memory' same 'ONO' with 'gate' with 'trench'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:20
S5	1474	@ad<="20030320" and (257/330-333).cccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:21
S6	1065	@ad<="20030320" and (257/313-314).cccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:21
S7	3009	@ad<="20030320" and (257/315-316).cccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:21
S8	815	@ad<="20030320" and (257/317-319).cccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:21
S9	1308	@ad<="20030320" and (257/320-323).cccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 15:21
S10	325	@ad<="20030320" and 'split-gate flash memory'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 10:49
S11	1	"20020024081".PN.	US-PGPUB	OR	ON	2004/12/16 15:49
S12	1	"20010038118".PN.	US-PGPUB	OR	ON	2004/12/16 15:49
S13	1	"6391719".PN.	USPAT; USOCR	OR	ON	2004/12/16 15:50
S14	1	"6303439".PN.	USPAT; USOCR	OR	ON	2004/12/16 15:50
S15	1	"6124608".PN.	USPAT; USOCR	OR	ON	2004/12/16 15:51

S16	1	"6124608".PN.	USPAT; USOCR	OR	ON	2004/12/16 15:51
S17	1	"5606521".PN.	USPAT; USOCR	OR	ON	2004/12/16 15:51
S18	3	@ad<="20030320" and 'split-gate' with 'flash memory' same 'selective gate'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 16:22
S19	467	@ad<="20030320" and 'split-gate' with 'flash memory' same 'gate'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/17 09:34
S20	72	@ad<="20030320" and 'split-gate' with 'flash memory' same 'gate' with 'trench'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/16 16:23